

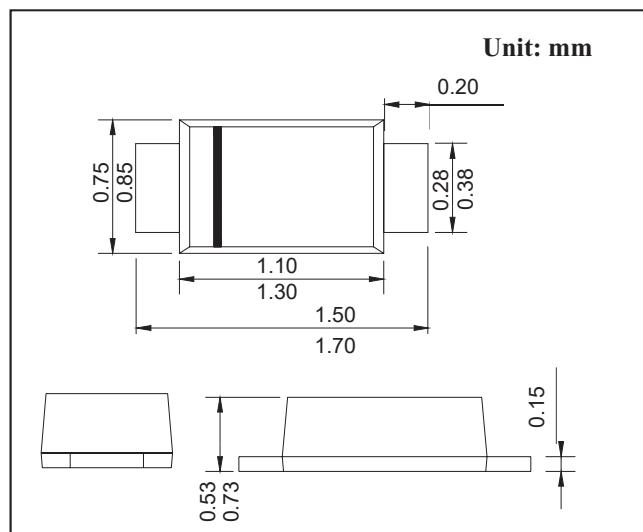
SOD523 Small Signal Switching Diodes

FEATURES

- Fast switching devices
- Low Reverse Current
- Matte Tin (Sn) Lead finish
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance

MECHANICAL DATA

- Case: SOD-523 Micro SMD package
- Polarity: Color band denotes cathode end
- Mounting Position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RM}	Non-Repetitive Peak Reverse Voltage	100	V
V_R	Reverse Voltage		
V_{RRM}	Peak Repetitive Reverse Voltage	75	V
V_{RWM}	Working Peak Reverse Voltage		
$V_{R(RMS)}$	RMS Reverse Voltage	53	V
I_o	Average Rectified Output Current	150	mA
I_{FM}	Forward Continuous Current	300	mA
I_{FSM}	Non-repetitive Peak Forward Surge Current@t= 8.3ms	2	A
P_D	Power Dissipation	150	mW
R_{eJA}	Thermal Resistance from Junction to Ambient	833	°C/W
T_j	Junction Temperature	150	°C
T_{stg}	Storage Temperature	-55~+150	°C

Electrical Specification ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=1\mu\text{A}$	75			V
Reverse current	I_R	$V_R=75\text{V}$			1	μA
		$V_R=20\text{V}$			25	nA
Forward voltage	V_F	$I_F=1\text{mA}$			0.715	V
		$I_F=10\text{mA}$			0.855	V
		$I_F=50\text{mA}$			1	V
		$I_F=150\text{mA}$			1.25	V
Total capacitance	C_{tot}	$V_R=0\text{V}, f=1\text{MHz}$			2	pF
Reverse recovery time	t_{rr}	$I_F = I_R = 10\text{mA}, I_{rr}=0.1*I_R, R_L=100\Omega$			4	ns

RATINGS AND CHARACTERISTIC CURVES

